Czech Contribution to Athena

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Abstract

We describe the recent status of the Czech contribution to the ESA Athena space mission, with emphasis on the development of new technologies and test samples of X-ray mirrors with precise surfaces, based on new materials, and their applications in space. In addition, alternative X-ray optical arrangements are investigated, such as Kirkpatrick-Baez systems.

1 Introduction

Design and development of X-ray optics have a long tradition in the Czech Republic (e.g. Hudec et al., 1991, 1999, 2000, 2001, Inneman et al. 1999, 2000). A range of related technologies have been exploited and investigated, including technologies for future large light-weight X-ray telescopes.

Future large space X-ray telescopes (such as Athena, considered by ESA [16]) require precise light-weight X-ray optics based on numerous thin reflecting shells. Novel approaches and advanced technologies need to be developed and exploited. In this paper, we refer to Czech efforts in connection with Athena, focusing on the results of test X-ray mirror shells produced by glass thermal forming (GTF) and by shaping Si wafers. Both glass foils and Si wafers are commercially available, have excellent surface microroughness of a few 0.1 nm, and low weight (the volume density is 2.5 g·cm⁻³ for glass and 2.3 g·cm⁻³ for Si). Technologies need to be exploited for shaping these substrates to achieve the required precise X-ray optic geometries without degrading the fine surface microroughness.

Although glass and, more recently, silicon wafers have been considered the most promising materials for future advanced large aperture X-ray telescopes, other alternative materials are also worth further study, such as amorphous metals and glassy carbon (Marsh et al., 1997). In order to achieve sub-arcsec angular resolutions, the principles of active optics need to be adopted. The Athena X-ray observatory is a new X-ray telescope of the European Space Agency (ESA). This project supersedes I XO (International X-ray Observatory) as well as NASA’s Constellation-X concept and also ESA’s XEUS mission concept (White et al., 2009). The spacecraft configuration for the Athena study is a mission featuring two large X-ray telescopes, each with an optical bench with a focal length of approx. 11.5 m and a suite of focal plane instruments. The Athena mission concept was presented and discussed in detail at the 1st Athena science meeting held at MPE in Garching, Germany, in June 2011 [16].

2 Czech contribution to Athena-related studies

At the moment, the Czech contribution to Athena concentrates on: (1) participating in defining scientific goals, justification and project preparation, (2) participating in the design and development of mirror technologies. The first author of this paper was delegated as a member of the Athena Telescope Working Group. In mirror development, we focus on supporting ESA ESTEC micropore silicon technology design and also on designing and developing alternative background technologies and designs, as discussed in greater detail below. Originally, these technologies were studied for the ESA/NASA/JAXA I XO project, but we believe that at least some of them might be valuable for Athena.

3 The glass foil option

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was either flat or curved (cylindrical or parabolic). The project continued with larger samples (up to 300 × 300 mm) and further profiles. Recent efforts have focused on optimizing the relevant parameters of both glass material and substrates, as well as the parameters of the slumping process.

Various approaches have been investigated. We note that these are not quite identical with efforts by other teams (e.g. Zhang et al., 2010, Ghigo et al., 2010). The glass samples were thermally formed at Rigaku, Prague, and also at the Institute of Chemical Technology in Prague. For large samples (300 × 300 mm), facilities at the Optical Development Workshop in Turnov were used. The strategy is to develop a technology suitable for inexpensive mass production of thin X-ray optics shells, i.e., to avoid expensive mandrels and techniques that are not suitable for mass production, or that are too expensive. Numerous glass samples have been shaped and tested in order to find the optimal parameters. The shapes and profiles of both mandrels, as well as the resulting glass replicas, have been carefully measured using metrological devices. The results show that the quality of the thermal glass replica can be significantly improved by optimizing the material and improving the design of the mandrel, by modifying the thermal forming process, as well as by optimizing the temperature. After the modifications and improvements, some of them significant, we obtained the resulting deviation of the thermally formed glass foil from the ideal designed profile to be less than 1 μm (peak to valley value) in the best case. This value is, however, strongly dependent on the exact temperature, so we believe that further improvements are still possible.

The fine original microroughness (typically better than 1 nm) of the original float glass foil was found not to be degraded by the thermal forming process. We note that our approach in thermal glass forming is different from the approaches used by other authors. Recent efforts have been devoted to optimizing the whole process, using and comparing different forming strategies etc., as the final goal is to further improve the forming accuracy to less than 0.1 μm values. For the near future, we plan to continue these efforts together with investigations of computer-controlled forming of glass foils (according to the principles of active optics).

4 The silicon wafer option

Silicon is a relatively light material and already during the manufacturing process it is lapped and polished (either on one side or on both sides) to very fine smoothness (better than a few 0.1 nm) and thickness homogeneity (of the order of 1 μm). Another obvious option, recently considered as one of most promising for high-precision X-ray optics for Athena, is the use of X-ray optics based on commercially available silicon wafers manufactured mainly for the purposes of the semiconductor industry.

The main advantages of the application of Si wafers in space X-ray optics are (i) the volume density, which is more than 3 times lower than the electroformed nickel used in the past for galvanoplastic replication of multiply nested X-ray mirrors, and slightly less than the alternative approach of glass foils, (ii) very high thickness homogeneity, typically less than 1 μm over 100 mm, and (iii) very small surface microroughness either on one side or on both sides (typically of the order of a few 0.1 nm or even less). Silicon wafers were expected to be used in the ESA XEUS and IXO projects, and are still under consideration for the Athena project. The recent baseline optics for the Athena X-ray telescope design is, like XEUS and IXO, based on X-Ray High Precision Pore Optics (X-HPO), a technology currently under development with ESA funding (RD-Opt, RD-HPO), with a view to achieving large effective areas with low mass, reduced telescope length, high stiffness, and a monolithic structure, favoured for handling the thermal environment and for simplifying the alignment process (Bavdaz et al. 2010). In addition, due to the higher packing density and the associated shorter mirrors required, conical approximation to the Wolter-I geometry becomes possible. X-HPO optics is based on ribbed Si wafers stacked together. The Si wafers for achieving the conical approximation are formed by stacking a large number of plates together using a mandrel. The typical size of the Si wafers is 10 × 10 cm.

There are also alternative X-ray optics arrangements with the use of Si wafers. In this paper, we refer to the development of an alternative design of innovative precise X-ray optics based on Si wafers. Our approach is based on two steps, namely (i) developing dedicated Si wafers with properties optimized for use in space X-ray telescopes, and (ii) precisely shaping the wafers to the optical surfaces (Figure 4). Stacking to achieve nested arrays is performed after the wafers have been shaped. In this approach, Multi Foil Optics (MFO) is thus created from shaped Si wafers. For more details on MFO, see Hudec et al. (2005).

This alternative approach does not require the Si wafers to have a ribbed surface, so problems with transferring any deviation, stress, and/or inaccuracy from one wafer to the neighbouring plates or even to the whole stacked assembly will be avoided. However, suitable technologies for precise stacking of optically formed wafers to a multiple array have to be developed.

The Si wafers available on the market are designed for use mainly in the semiconductor industry. It is obvious that the requirements of this industry
are not the same as the requirements of precise space X-ray optics. Si wafers are a monocrystal (single crystal) with some specifics, and this must also be taken into account. Moreover, Si wafers are fragile, and it is very difficult to bend and/or shape them precisely for the thicknesses required for X-ray telescopes, i.e. around 0.3–1.0 mm. An exception is thin Si wafers below 0.1 mm in thickness. However, these can be hardly used in this type of X-ray optics because of diffraction limits. Also, while their thickness homogeneity is mostly perfect, the same is not true in the case of commercially available wafers for their flatness (note that we refer here to the deviation of the upper surface of a free-standing Si wafer from the ideal plane, while in the semiconductor community flatness is usually represented by a set of parameters).

In order to achieve the very high accuracy required by ESA for future large space X-ray telescopes like Athena, the parameters of the Si wafers need to be optimized (for application in X-ray optics) at the production stage. For this purpose we have established and developed a multidisciplinary working group including specialists from the development department of the Si wafer industry with the goal to design and manufacture Si wafers with improved parameters (mostly flatness) optimized for application in X-ray telescopes. It should be noted that the manufacture of silicon wafers is a complicated process with numerous technological steps and with many free parameters that can be modified and optimized to achieve optimal performance. This can also be useful for further improving the quality of X-HPO optics. As we are dealing with high-quality X-ray imaging, the smoothness of the reflecting surface is important. The standard microroughness of commercially available Si wafers (we have used the products of ON Semiconductor, Czech Republic) is of the order of 0.1 nm, as confirmed by several independent measurements using various techniques including the Atomic Force Microscope (AFM). This is related to the method of chemical polishing used in the manufacture of Si wafers. The microroughness of Si wafers exceeds the microroughness of glass foils and most other alternative mirror materials and substrates. The flatness (in the sense of the deviation of the upper surface of a free-standing Si wafer from a plane) of commercially available Si wafers was however found not to be optimal for use in high-quality (order of arcsec angular resolutions) X-ray optics. Most Si wafers show deviations from the plane of the order of a few tens of microns. After modifying the technological process during Si wafer manufacture, we were able to reduce this value to just a few microns. Also, the thickness homogeneity was improved. In collaboration with the manufacturer, further steps are planned to improve the flatness (deviation from an ideal plane) and the thickness homogeneity of Si wafers. These and planned improvements introduced at the Si wafer manufacture stage can also be applied for other designs of Si wafer optics including X-HPO, and can play a crucial role in the Athena project.

The X-ray optics design for Athena is based on the Wolter 1 arrangement, and hence requires curved surfaces. However, due to the material properties of monocrystalline Si, Si wafers (except very thin ones) are extremely difficult to shape. It is obvious that we have to overcome this problem in order to achieve the fine accuracy and stability required for future large X-ray telescopes. The final goal is to provide optically shaped Si wafers with no or little internal stress. Three different alternative technologies for shaping Si wafers have been designed and tested to achieve precise optical surfaces (Figure 1). The samples shaped and tested were typically 100 to 150 mm large, typically 0.6 to 1.3 mm thick, and were bent to either cylindrical or parabolic test surfaces.

![Fig. 1: Example of precise silicon wafer shaping. After deposition of poly-Si (thickness 1 436 nm at temperature 615 °C) and for wafer thickness 507 μm, a warp of 110 mm (R = 25.6 m) was achieved. Left: Wafer deformation map. Right: Warp profile perpendicular to the facet](image)
The development described here is based on a scientific approach, and hence the large number of samples formed with different parameters must be precisely measured and investigated in detail. Especially precise metrology and measurements play a crucial role in this type of experiment. The samples of bent wafers with the investigated technologies have been measured, including Taylor-Hobson mechanical and STILL optical profilometry, as well as optical interferometry (ZYGO) and AFM (Atomic Force Microscope) analyses. It has been confirmed that all these three technologies do not degrade the intrinsic fine microroughness of the wafer. While the two physical/chemical technologies exploited give peak-to-valley (PV) deviations (of the real surface of the sample compared with the ideal optical surface) of less than 1 to 2 μm over the 150 mm sample length as preliminary values, the deviations of the first thermally bent sample are larger, of the order of 10 μm. Taking into account that the applied temperatures, as well as other parameters, were not optimized for this first sample, we anticipate that the PV (peak to valley) value can be further reduced down to the order of 1 μm and perhaps even below. Fine adjustments of the parameters can also further improve the accuracy of the results for the other two techniques.

5 The Kirkpatrick-Baez option

Although Wolter systems are generally well-known and widely used, Hans Wolter was not the first to propose X-ray imaging systems based on reflection of X-rays. In fact, the first grazing incidence system to form a real image was proposed by Kirkpatrick and Baez in 1948. This system consists of a set of two orthogonal parabolas of translation (Figure 2). The first reflection focuses to a line, which is focused by the second surface to a point. This was necessary to avoid the extreme astigmatism suffered by a single mirror, but it still was not free of geometric aberrations. Nevertheless, the system is attractive because it is easy to construct the reflecting surfaces. These surfaces can be produced as flat plates and then mechanically bent to the required curvature. In order to increase the aperture, a number of mirrors can be nested together, but it should be noted that this nesting introduces additional aberrations. This configuration is used mostly in experiments not requiring a large collecting area (solar, laboratory). The applications in X-ray astronomy and astrophysics were limited in the past, despite initial success on sounding rockets (e.g. Gorenstein et al., 1978). Nevertheless, large modules of Kirkpatrick-Baez (KB) mirrors based on float glass have also been suggested for stellar X-ray experiments (LAMAR experiment in KB configuration designed for the Shuttle experiment, e.g. Fabricant et al. 1988).

![Fig. 2: Multi Foil Optics (MFO) in the Kirkpatrick-Baez (K-B) arrangement](image)

Superior silicon substrates have recently become available that make it possible to consider designing large KB modules with this novel material. As mentioned above, Si wafers are difficult to shape, especially to small radii. To overcome this difficulty, another X-ray optics arrangement can be considered, namely the Kirkpatrick-Baez (KB) system. Then the curvature radii are much larger, of the order of a few km, while the imaging performance is similar. For the same effective area, however, the focal length of the KB system is about twice as large as the focal length of the Wolter system. Nevertheless, KB systems represent a promising alternative to the classical Wolter systems in future large space X-ray telescopes.

A very important factor is the ease (and hence the reduced cost) of constructing highly segmented modules based on multiply nested thin reflecting substrates, in comparison with the Wolter design. While e.g. the Wolter design for Athena requires the substrates to be precisely formed with curvatures as small as 0.25 m, the alternative KB arrangement uses almost flat or only slightly bent sheets. Hence the feasibility of constructing a KB module with the required 5 arcsec FWHM at an affordable cost is higher than for the Wolter arrangement.

Advanced KB telescopes are based on the Multi Foil Optics (MFO) approach (X-ray grazing incidence imaging optics based on numerous thin reflecting substrates/foils). The distinction between MFO and other optics using packed or nested mirrors is that MFO is based on numerous very thin (typically less than 0.1 mm) substrates. The MFO KB test modules were recently designed and constructed at Rigaku Innovative Technologies Europe (RITE) in Prague, and 2 modules were tested in full aperture X-ray tests in the test facility of the University of Boulder, with preliminary results of FWHM 26 arcsec for a full stack of 24 standard Si plates at 5 keV, and even better for glass foils and 1D imaging (Figures 3, 4).
In our opinion, the use of KB design instead of Wolter in Athena might help to retain high performance (such as effective area) even in the event of a reduced budget for Athena.

6 Conclusion

Suitable technologies for future large X-ray telescopes require extensive research work. Two promising technologies suitable for future large-aperture and fine resolution X-ray telescopes, such as Athena, were exploited and investigated in detail, namely Glass Thermal Forming and Si wafer bending. In both cases, promising results have been achieved, with peak-to-valley deviations of the final profiles from the ideal profiles being of the order of 1 μm in the best cases, with space for further essential improvements and optimization. In the Czech Republic, an interdisciplinary team with 10 members is cooperating closely with experienced specialists, including researchers from a large company producing Si wafers. Si wafers have been successfully bent to the desired geometry by three different techniques. In the best cases, the accuracy achieved for a 150 mm Si wafer is 1–2 μm for deviation from the ideal optical surface. Experiments are continuing in an attempt to further improve the forming accuracy.

As an alternative, we have investigated the KB option for Athena, with quite promising results justifying further efforts in this direction. A major advantage of KB is its low cost, as there is no need for bending to small curvatures and/or for the use of (expensive) mandrels. Less expensive optics can maintain a high effective area even on a reduced budget.
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